Product data sheet

1. General description

Standard reverse recovery power diode in a TO-220F package.

2. Features and benefits

- · Low forward voltage drop
- Low leakage current
- · High voltage capability
- · High inrush current capability

3. Applications

- · Input rectifier
- · Regulator diode

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Values			Unit
Absolute	maximum rating						
V_{RRM}	repetitive peak reverse voltage		1600			V	
I _{F(AV)}	average forward current	$δ = 0.5$; square-wave pulse; $T_h \le 113$ °C; Fig. 1; Fig. 2; Fig. 3	8			А	
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	180			А	
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse		2	16		Α
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static characteristics							
V _F	forward voltage	I _F = 8 A; T _j = 25 °C; <u>Fig. 6</u>		-	-	1.2	V
		I _F = 8 A; T _j = 150 °C; <u>Fig. 6</u>		-	-	1.1	V

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	Α	anode	mb	K — A
2	K	cathode		001aaa020
mb	n.c.	mounting base; isolated		

6. Ordering information

Ta	ıhl	e	3	. ()ri	der	ina	inf	formation

Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
WND08P16X	TO-220F	WND08P16XQ	Tube	50	TO-220F	14-Apr-2014

7. Marking

Table 4. Marking codes

Type number	Marking codes
WND08P16X	WND08P16X

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8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V_{RRM}	repetitive peak reverse voltage		1600	V
V_{RWM}	crest working reverse voltage		1600	V
V_R	reverse voltage	DC	1600	V
I _{F(AV)}	average forward current	$δ$ = 0.5 ; square-wave pulse; $T_h \le 113$ °C; Fig. 1; Fig. 2; Fig. 3	8	Α
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	180	А
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	216	А
T _{stg}	storage temperature		-55 to 150	°C
T _j	junction temperature		150	°C

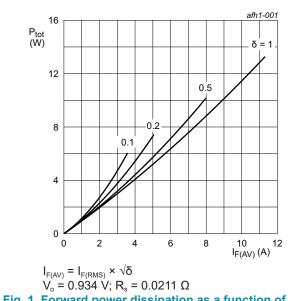
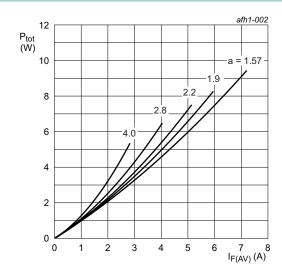
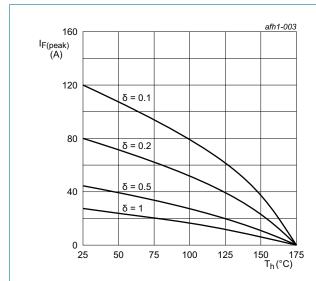


Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



a = form factor = $I_{F(RMS)}/I_{F(AV)}$ V_o = 0.934 V; R_s = 0.0211 Ω

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values





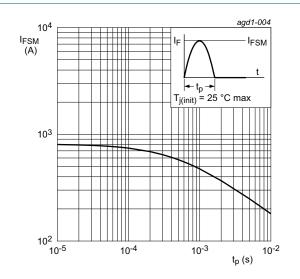
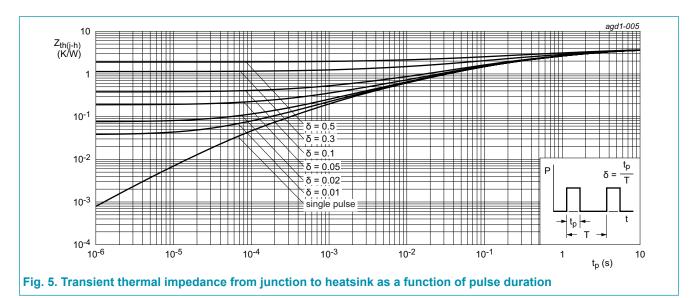


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-h)}$	thermal resistance from junction to heatsink	<u>Fig. 5</u>	-	-	3.6	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	in free air	-	55	-	K/W



10. Isolation characteristics

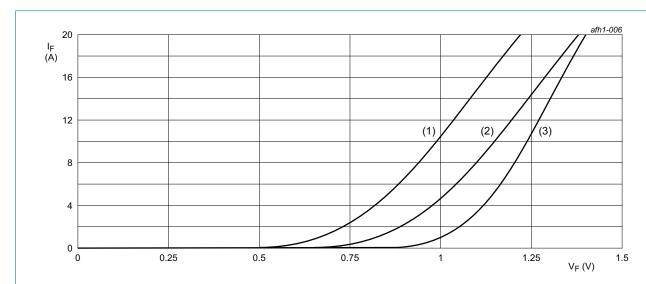
Table 7. Isolation characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{isol(RMS)}	RMS isolation voltage	50 Hz \leq f \leq 60 Hz; RH \leq 65 %; from all pins to external heatsink; sinusoidal waveform; clean and dust free	-	-	2500	V
C _{isol}	isolation capacitance	from cathode to external heatsink	-	10	-	PF

11. Characteristics

Table 8. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
V _F	forward current	I _F = 8 A; T _j = 25 °C; <u>Fig. 6</u>	-	-	1.2	V
		I _F = 8 A; T _j = 150 °C; <u>Fig. 6</u>	-	-	1.1	V
I _R	reverse current	V _R = 1600 V; T _j = 25 °C	-	-	50	μΑ
		V _R = 1600 V; T _j = 150 °C	-	-	1.5	mA

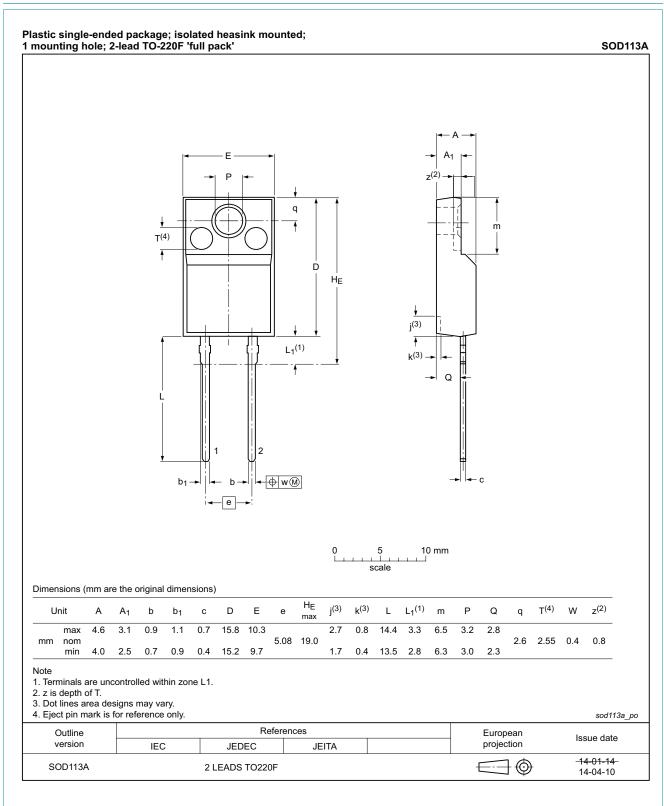


 $V_o = 0.934 \text{ V}; R_s = 0.0211 \Omega$

(1) $T_j = 150$ °C; typical values (2) $T_j = 150$ °C; maximum values (3) $T_j = 25$ °C; maximum values

Fig. 6. Forward current as a function of forward voltage

12. Package outline



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Standard power diode

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